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An analytic approach to modeling the optical response of anisotropic nanoparticle arrays at surfaces and interfaces

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Abstract

Anisotropic nanoparticle (NP) arrays with useful optical properties, such as localized plasmon resonances (LPRs), can be grown by self-assembly on substrates. However, these systems often have significant dispersion in NP dimensions and distribution, which makes a numerical approach to modeling the LPRs very difficult. An improved analytic approach to this problem is discussed in detail and applied successfully to NP arrays from three systems that differ in NP metal, shape and distribution, and in substrate and capping layer. The materials and anisotropic NP structures that will produce LPRs in desired spectral regions can be determined using this approach.

Keywords: plasmonics, optical response, anisotropic, arrays, modeling

(Some figures may appear in colour only in the online journal)

1. Introduction

Metallic nanoparticles (NPs) have excitation modes that are highly localized and decay rapidly within the structures, resulting in localized plasmon resonances (LPRs) [1, 2]. These excitation modes have been the subject of considerable interest due to their potential application in areas such as biological sensors [3–6], enhancement effects [7–9] and solar cell applications [10–12]. One of the key aspects of LPRs is the possibility of tuning the resonance position by altering the NP size, shape and aspect ratio, by modifying the NP distribution in, or on, the host material, and by varying the host material itself [13].

Recently, polarization-dependent optical methods have been demonstrated to be a very useful tool for both characterization of LPRs and for practical applications. Phase sensitive methods, such as spectroscopic ellipsometry (SE) [14], have been demonstrated to have a striking advantage in sensitivity [15, 16], up to single molecule recognition [17]. Another polarization method, reflectance anisotropy spectroscopy (RAS), has been used to monitor the evolution of NP arrays growing on faceted \(\alpha\)-Al\(_2\)O\(_3\) surfaces by self-assembly [18–20]: structures with LPRs covering the whole visible range can be produced using this approach [21].

NP arrays grown on planar surfaces by lithographic techniques typically have periodic structures of NPs with high symmetry, which allows the use of numerical solutions of Maxwell’s equations to determine the optical response, such as boundary element [22] and finite difference time domain methods [23]. The anisotropic NP arrays grown on surfaces...
by self-assembly, however, have significant dispersion in NP dimensions and distribution, which makes a numerical approach very difficult. Analytic solutions exist for regular arrays of spheroidal NPs supported on substrates, where the rotational axis of the NP is normal to the surface [24], and these have been used to model polarized absorption spectra [25, 26]. Exact analytic solutions have not been published for the ellipsoidal, or flattened ellipsoidal, NPs that typically grow by self-assembly.

A basic analytic approach for estimating the optical response of such anisotropic systems has been outlined that provides reasonable agreement with experiment for Ag NP arrays grown by glancing angle deposition onto facetted α-Al2O3 under high vacuum conditions [16, 20]. Here an improvement to this approach is discussed in detail and applied successfully to NP arrays from three systems that differ in NP metal, shape and distribution, and also in substrate and in capping layer. Anisotropic NPs typical of self-assembled growth, anisotropic arrays grown on structured substrates, tarnish shells, and single or multiple capping layers can all be modeled, using only the thickness and the mixing fraction for the effective medium of the NP layer as free parameters to be optimized for particular material systems. The materials and anisotropic NP structures that will produce LPRs in desired spectral regions can be determined using this improved analytic approach.

2. Experiment

The experimental procedures used for the growth and characterization of the three distinct plasmonic systems have been reported in detail previously [18, 27, 28]. In the first system, anisotropic Pb nanostructures were grown on clean Si(5 5 7) surfaces by self-assembly under ultra-high vacuum (UHV) conditions [27]. Gold and Pb were deposited from molecular beam epitaxy cells, and α-Si was evaporated using a sublimation source. Deposition of 0.18 monolayers (ML) of Au onto the vicinal Si surface produces aligned, single height atomic steps, which act as a template for the growth of highly anisotropic Pb islands [29]. Deposition of Au and Pb was monitored optically using a visible/near-IR (0.45–5 eV) RAS system, which uses photoelastic modulation (PEM) to change the polarization state of the light [30]. This technique has been shown to be a sensitive probe of aligned, anisotropic phases grown on vicinal Si surfaces [31–33]. RAS measures the difference in reflectance, at near normal incidence, of light linearly polarized in two orthogonal directions at the surface plane of a cubic material [34]:

$$\frac{\Delta r}{r} = 2 \frac{r_x - r_y}{r_x + r_y}$$

where $r_x$ and $r_y$ are the complex Fresnel reflection coefficients for the surface for light polarized in the $x$ and $y$ directions, with the steps and long axis of the Pb islands running in the $x$ direction. For the Si/Pb system a rotating sample RAS system was used to extend the spectral range of the RAS measurements down to 0.12 eV in the ambient, using a Coherent Ti : sapphire–regenerative amplifier–optical parametric amplifier–DFG system that produced linearly polarized 130 fs pulses, with a 100 kHz repetition rate, tuneable from 0.12 to 0.5 eV in the IR [27]. In situ optical measurements were repeated after the Pb nanostructures had been capped with 4.5 nm of α-Si.

Anisotropic Ag nanostructures were grown by self-assembly using two different techniques on two different substrates. Glancing angle deposition onto facetted α-Al2O3 under high vacuum conditions, using a collimated Ag flux, produced arrays of anisotropic Ag NPs decorating the facets [18]. Growth was monitored in situ using the PEM-based RAS. The second technique used was the deposition of Ag onto native-oxide-covered rippled Si(0 0 1) substrates under high vacuum conditions. The substrates were produced at the Helmholtz–Zentrum Dresden–Rossendorf using a procedure that has been described in detail previously [35, 36]. Briefly, the rippled structure with ~30 nm periodicity and ~1 nm amplitude, measured by atomic force microscopy (AFM), were prepared by irradiating native-oxide-covered Si(0 0 1) substrates at room temperature with a collimated beam of 500 eV Ar+ ions, aligned with the <1 0 0> azimuth and at an angle of 67° with respect to the surface normal. Fluences in the range ~1016–~1019 ions cm–2 were used [37]. After ex situ characterization, Ag was deposited perpendicularly to the ripples on the native-oxide-covered surface by electron beam evaporation at an incidence angle of 70°, followed by sample annealing at 350 °C. RAS and SE were used to monitor the linear optical response in the ambient for both types of Ag nanostructures.

3. Theory

Analytic solutions for NP systems exist for spheroidal particles, including truncated caps, on surfaces or embedded at interfaces, but none exist where a rotational axis normal to the surface or interface is absent [24]. An approximate analytic theory is developed here that provides a reasonable description of the plasmonic resonances of these three very different anisotropic NP systems. The procedure involves determining the anisotropic polarizability of an isolated ellipsoidal NP, then estimating the dielectric response of the NP layer, and finally calculating the optical response of the multilayer system. This approximate analytic approach for anisotropic systems provides reasonable agreement with experiment and thus may be used to guide the choice of materials and growth parameters for the fabrication of aligned anisotropic NP arrays for producing LPRs in particular spectral regions.

3.1 The isolated NP

The dielectric function of the metal NP, some or all of whose dimensions are shorter than the electron inelastic scattering mean free path in the bulk metal, is modified in direction $j$ to account for the increased scattering rates from the boundaries of the ellipsoidal NP [38] and becomes anisotropic:
The plasmon effective mass \[39\]. The semi-axes of the ellipsoid and the Fermi velocities vary with crystal orientation but Ag has a Pb value almost an order of magnitude larger than that of Ag. The increase in scattering rate leads to ~0.2 and ~2 \[40–42\]. The thickness of the local field, which differs from the external applied field. The anisotropic polarizability of an ellipsoid of volume \(V = 4\pi R_R R_L / 3\) is

\[\alpha_j = V \frac{\varepsilon_j - \varepsilon_{cap}}{\varepsilon_{cap} + L_j(\varepsilon_j - \varepsilon_{cap})} \tag{5}\]

where \(L_j\) is the shape depolarization factor for ellipsoidal particles, accounting for the local field experienced by a single NP, and \(\varepsilon_j\) is the anisotropic dielectric function of the metal NP introduced above \[1\]. The quasi-static approximation is used in obtaining equation (5), which is an adequate approach for NP systems where no multipolar modes or multiple scattering effects are observed. The modified long wavelength approximation can be used for larger particles to take into account retardation effects \[50\].

The standard depolarization factors for isolated ellipsoidal NPs are expressed as

\[L_j = \frac{j k l}{2} \int_0^\infty \frac{dq}{(j^2 + q^2)(k^2 + q^2)(l^2 + q^2)}, \tag{6}\]

where \(j, k, l\) are the semi-axes of the ellipsoid and the sum rule follows from evaluating the integral \[51\]. The effect of anisotropic local fields is to split the resonance into three components.

A theoretical treatment of the \(A\) parameter for Ag identified a free NP size-dependent term and a NP interface term that depends on the surrounding medium and adsorbates \[49\]. The interface contribution varies with capping layer dielectric function, and the contribution from the perpendicular component of the interface term was shown to be smaller. Values in the middle of the calculated range were chosen and used for both Ag and Pb NPs. The three scattering rates in equation (2), in eV, become

\[\gamma_r = \gamma_b + 0.65 \left( \frac{\hbar}{e} \right)^{\nu_F} R_b, \quad \gamma_y = \gamma_b + 0.65 \left( \frac{\hbar}{e} \right)^{\nu_F} R_y, \quad \gamma_z = \gamma_b + 0.4 \left( \frac{\hbar}{e} \right)^{\nu_F} R_z. \tag{4}\]

Using these expressions removes \(A\) as a variable and appears to produce reasonable lineshapes.

### 3.2 The NP in a dielectric environment

When the NP is embedded in an environment with a dielectric function of \(\varepsilon_{cap}\), the field experienced by the NP is modified by the local field, which differs from the external applied field. The dielectric function of the substrate and \(\varepsilon_{cap}\) is the dielectric function of the medium surrounding the sphere \(\varepsilon_{cap} = 1\) for uncapped samples \[53\]. However, interfacial NP layers are heterogeneous and may be rough, suggesting an effective medium dielectric function, \(\varepsilon_{eff}\) should be used. There are well known formulae \[54\], such as Maxwell-Garnett and Bruggeman, for spherical inclusions, which can be adapted for ellipsoidal NPs. Different approaches were explored, but the fundamental bounds to \(\varepsilon_{eff} [54]\) limited the shifts in resonance energies to ~0.2 eV. As the interfacial NP layer is generally not well defined, and the shifts are small, a simple arithmetic model was adopted: \(F = (\varepsilon_b - \varepsilon_{eff}) / (\varepsilon_b + \varepsilon_{eff})\), where \(\varepsilon_{eff} = (1 - f) \varepsilon_b + f \varepsilon_{cap}\).

### Table 1. Material parameters for bulk Ag and Pb.

<table>
<thead>
<tr>
<th>Material</th>
<th>(\omega_p) (eV)</th>
<th>(\gamma_b) (eV)</th>
<th>(v_F) (m/s)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ag</td>
<td>8.85 [48]</td>
<td>0.037 [48]</td>
<td>1.4x10^6 [46]</td>
</tr>
<tr>
<td>Pb</td>
<td>8.65</td>
<td>0.20</td>
<td>2.96x10^6 [47]</td>
</tr>
</tbody>
</table>
The mixing fraction \( f \) is allowed to vary from system to system to optimize agreement with experiment. For consistency, \( \epsilon_{\text{cap}} \) is replaced by \( \epsilon_{\text{eff}} \) in equation (5).

These expressions allow a particle to be located above the interface, but they also provide a simple way of adjusting the strength of the image charge interaction by varying \( d \). The standard spherical dipole approach, which places \( d \) at the center of the NP, is known to overestimate the interaction with the substrate. This affects the LPR response of all components, but particularly that of the \( z \)-component \([24, \text{chapter 6}]\), which provides a corrected value for \( d \). The ellipsoidal NPs are approximated as oblate spheroidal particles with the geometric average in-plane radius \([19]\), which allows an effective value of \( d \) to be determined from the analytic expressions:

\[
d_{\text{eff}} = \frac{1}{\sqrt{\left(2R_{x}R_{y}R_{z}\right)/\left(1+\frac{\xi_{0}^{2}}{R_{x}^{2}}\right)}}\left[\frac{1}{\left(2R_{x}^{2}+\xi_{0}^{2}/R_{x}^{2}\right)}\ln\left(1+\frac{\xi_{0}^{2}}{R_{x}^{2}}\right)\right]^{1/2}
\]

where

\[
\xi_{0} = R_{z}/\sqrt{R_{x}R_{y}R_{z}}.
\]

This provides a consistent way of adjusting \( d \) although, as the anisotropy of the NP increases, \( d_{\text{eff}} \) becomes unphysical.

Oxidation or tarnishing on exposing metallic NPs to the ambient is a common occurrence and the effect can be approximated by assuming that the NP is coated by a dielectric shell. The polarizability for a shell of thickness \( d_{\text{sh}} \) and dielectric function \( \epsilon_{\text{sh}} \) becomes \([51, 55]\):

\[
\alpha_{j} = \sqrt{\left(\epsilon_{\text{sh}} - \epsilon_{\text{eff}}\right)\left(\epsilon_{\text{sh}} - \epsilon_{\text{sh}}\right)}\left[\left(1 - f_{c}\right)L_{j}\right] + f_{c}\epsilon_{\text{sh}}\left(\epsilon_{\text{sh}} - \epsilon_{\text{sh}}\right)L_{j}
\]

where the core volume fraction of the NP is approximated by

\[
f_{c} = \left(\sqrt{R_{x}R_{y}R_{z}} + d_{\text{sh}}\right)^{3}.
\]

Where there is no shell, \( d_{\text{sh}} = 0 \) and \( \epsilon_{\text{sh}} = \epsilon_{\text{eff}} \), regaining equation (5).

### 3.3 The NP layer

The electromagnetic coupling between the NPs has to be considered when the NPs are assembled in a single layer at an interface. Within a point dipole coupling model, the layer dielectric functions are \([25, 52, 56]\)

\[
\epsilon_{\text{eff}}^{L} = \epsilon_{\text{eff}}\left(1 + \frac{\rho\alpha_{s}}{1 + \epsilon_{\text{eff}}\alpha_{s}\beta_{s}}\right)
\]

\[
\frac{1}{\epsilon_{\text{eff}}^{L}} = \frac{1}{\epsilon_{\text{eff}}}\left(1 - \frac{\rho\alpha_{s}}{1 + \epsilon_{\text{eff}}\alpha_{s}\beta_{s}}\right)
\]

where \( \rho \) is the volume density. The volume density becomes the surface density for the single layer NP systems considered here. The interaction parameters arising from the dipolar coupling are

\[
\beta_{x,y} = -\frac{1}{4\pi\epsilon_{\text{eff}}}(F_{x} + 2d) + \sum_{i}3\cos^{2}\theta_{i} - \frac{1}{r_{i}^{3}}
\]

\[
\beta_{z} = -\frac{1}{4\pi\epsilon_{\text{eff}}}(F_{z} + 2d) + \sum_{i}3\cos^{2}\theta_{i} - \frac{1}{r_{i}^{3}}
\]

where \( \theta_{i} \) is the dipole angle, \( r_{i} \) is the separation of the point dipole from the central particle, \( \theta_{i} \) is the image dipole angle, and \( r_{i} \) is the separation of the image point dipole from the central particle.

The first term is the self-image interaction, the second term is the dipole interaction, and the third term is the image dipole interaction. The NPs are assumed to form a rectangular lattice, with a center-to-center spacing of \( l_{x} \) and \( l_{y} \) (\( \rho = 1/l_{x}l_{y} \), and the average NP layer thickness is \( \rho V \)). Summing over a \( 20 \times 20 \) lattice is sufficient to reduce the finite sum error to less than 5%. In addition, the contribution at large separations is overestimated in equations (11a) and (11b) because retardation, which reduces the dipolar contribution due to decoherence, is neglected.

### 3.4 The optical response of the multilayer system

The effective dielectric function of the NP layer is treated as one layer of the full optical model of the multilayer system, which uses the transfer matrix approach. This was originally formulated for isotropic media \([57]\), but has been extended by Berreman \([58]\) and by Schubert \([59, 60]\) to produce a more general form applicable to anisotropic layers. Following this approach, a four-vector is defined for the \( s- \) and \( p- \) polarized components of the electric and magnetic field, and each layer can be then defined by a \( 4 \times 4 \) partial transfer matrix, \( T_{i} \). Knowing the thickness and dielectric properties of each layer allows the partial transfer matrix of each individual layer to be calculated and the full response of the system derived in the form of complex reflection coefficients, which can be compared with experiment. In outline,

\[
T_{i} = \exp(i\omega d / c) = \beta_{s}I + \beta_{x}A + \beta_{y}A^{2} + \beta_{z}A^{3}
\]

where \( d = \rho V \), the average NP layer thickness and the complex \( \beta_{i} \) must obey the following set of equations:

\[
\exp(i\omega d q_{k} / c) = \sum_{j=0}^{\infty}q_{j}^{k}, \quad k = 1, ..., 4
\]

where \( q_{k} \) are the eigenvalues of \( A \) (appendix) \([60]\). The total matrix is obtained by multiplying the inverse of the incident matrix, \( L_{in} \), the partial transfer matrices, \( T_{i} \), of the \( N \) layers, and the exit matrix, \( L_{out} \):
Table 2. Parameters for Si(5 5 7)-5×1-Au/8 ML Pb, and Si (5 5 7)-5×1-Au/8 ML Pb/4.5 nm α-Si. The range of experimental values was determined from SEM images.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Experiment</th>
<th>Model</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_x$ (nm)</td>
<td>85–215</td>
<td>110</td>
</tr>
<tr>
<td>$R_y$ (nm)</td>
<td>30–90</td>
<td>35</td>
</tr>
<tr>
<td>$l_x$ (nm)</td>
<td>6 [61]</td>
<td>6.5</td>
</tr>
<tr>
<td>$l_y$ (nm)</td>
<td>360–620</td>
<td>390</td>
</tr>
<tr>
<td>Island density $\rho = 1 / l_x l_y (\mu m^{-2})$</td>
<td>7–25</td>
<td>18</td>
</tr>
<tr>
<td>Average NP layer thickness (nm)</td>
<td>2.3(2)</td>
<td>1.9</td>
</tr>
<tr>
<td>RAS scaling factor</td>
<td>-</td>
<td>0.13</td>
</tr>
<tr>
<td>Capping layer thickness (nm)</td>
<td>4.5</td>
<td>4.5</td>
</tr>
<tr>
<td>Effective medium $f$</td>
<td>-</td>
<td>0.5</td>
</tr>
</tbody>
</table>

$$T = L_x^{-1} \prod_{j=1}^{N} T_{ij} (-d_i) L_j.$$ (14)

The incident and exit matrices are given in the appendix. The complex reflection coefficients required are found from the components of $T$:

$$r_{ix} = (T_{1x} T_{13} - T_{3x} T_{31}) / \Delta T \quad \text{and} \quad r_{ix} = (T_{1x} T_{13} - T_{3x} T_{31}) / \Delta T$$

where $\Delta T = T_{11} T_{33} - T_{13} T_{31}$.

Finally, the measured quantities are expressed in terms of the reflection coefficients. For RAS,

$$\Delta r \frac{r}{r} = 2 \frac{r_{pp} - r_{ss}}{r_{pp} + r_{ss}}$$ (16)

with normally the real part of $\Delta r / r$ being measured. For SE, it is the complex pseudo-dielectric function, $\langle \varepsilon \rangle_i$, $i = x, y$, that can be determined directly from measurements in the $xz$ and $yz$ optical plane:

$$\langle \varepsilon \rangle_i = \sin^2 \theta + \sin^2 \theta \tan^2 \phi \left( \frac{T_{i3} T_{33} - T_{i1} T_{13}}{T_{i3} T_{33} + T_{i1} T_{13}} \right)^2$$ (17)

where $\theta$ is the angle of incidence and the principle axes of the layers are aligned with the laboratory axes [59]. This approach can be simply extended to multiple capping layers.

The dielectric functions of the NP material, substrate and capping layer are known, leaving seven variable parameters, which were adjusted manually: the NP dimensions and spacing, the mixing fraction for the effective medium of the NP layer, and a RAS scaling factor chosen to reproduce the experimental $x$ resonance peak height. The last factor is included as RAS is only directly sensitive to anisotropic NPs, while the experimental NP surface density will generally count all the NPs.

4. Results and discussion

4.1 LPRs of Pb islands grown on Si (5 5 7)-5×1-Au

Analysis of the SEM images of the 8 ML coverage reveals islands of typical width 60 nm, with some coalescing into islands of double or triple that width. The length distribution was from 170 to 430 nm. Previous work has indicated that the height of the islands is relatively uniform at 12 nm in this coverage region [61]. For 8 ML Pb, 30% of the surface was covered in islands. Table 2 records the large variation in island size, shape and distribution, as this is more useful than average values. Figure 1(a) shows the real RAS response from uncapped Si(5 5 7)-5×1-Au/8 ML Pb, where the inset shows a typical SEM image. The noisier data below 0.45 eV were recorded with the rotating sample laser RAS assembly. Figure 1(b) is the response of the same sample capped with 4.5 nm of α-Si, as measured using a quartz crystal oscillator. These experimental data have been reported previously [27], where a simple antenna model [62] produced reasonable agreement with the $x$-LPR position, but the model does not address the other resonances, nor the line shape and intensity.

Two large structures can be seen in the IR region of the uncapped spectrum: a minimum at 1.13 eV (y-LPR) and a maximum at 0.47 eV ($x$-LPR). RAS is a normal incidence technique and does not probe the $z$-LPR. The laser RAS, while quite noisy, confirms the presence and position of the maximum, which lies outside the spectral range of conventional RAS instruments. Capping then red-shifts the peaks to 0.9 eV and 0.42 eV, respectively, reduces their width, and increases the relative contribution of the $y$-LPR. The
experimental data are compared with the model parameters in table 2. The same model parameters are used for both capped and uncapped samples, the only change being the addition of the capping layer of α-Si. The dielectric function of the α-Si was determined from SE measurements of a similar α-Si layer grown under the same conditions on native-oxide-covered Si(0 0 1). The model captures the position and shape of both spectra satisfactorily, using parameter values that are consistent with the experimental data. The peak width is dominated by the bulk plasmon contribution, because the inelastic scattering length of ~10 nm is much smaller than the island dimensions. The effective medium chosen was the average of the substrate and vacuum, or substrate and capping layer, as appropriate. Reasonable results are obtained when modeling the uncapped and capped spectra using a single parameter set, which is a quite severe test of the model. No additional structure indicative of quadrupolar contributions can be seen. The overall agreement is impressive, particularly when it is clear from the inset in figure 1(a) that the NP shapes are faceted and only very approximately ellipsoidal.

Table 3. Parameters for Ag NPs grown on faceted α-Al₂O₃.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Experiment [63]</th>
<th>Model</th>
</tr>
</thead>
<tbody>
<tr>
<td>( R_x (\text{nm}) )</td>
<td>9.3(2.3)</td>
<td>10.0</td>
</tr>
<tr>
<td>( R_y (\text{nm}) )</td>
<td>7.7(1.4)</td>
<td>6.5</td>
</tr>
<tr>
<td>( R_z (\text{nm}) )</td>
<td>-</td>
<td>5.0</td>
</tr>
<tr>
<td>( l_x (\text{nm}) )</td>
<td>24(6)</td>
<td>22</td>
</tr>
<tr>
<td>( l_y (\text{nm}) )</td>
<td>120(35)</td>
<td>130</td>
</tr>
<tr>
<td>Island density ( \rho = 1/l_x l_y (\mu m^{-2}) )</td>
<td>350(130)</td>
<td>350</td>
</tr>
<tr>
<td>Average NP layer thickness (nm)</td>
<td>3.5(5)</td>
<td>0.5</td>
</tr>
<tr>
<td>RAS scaling factor</td>
<td>-</td>
<td>1.0</td>
</tr>
<tr>
<td>Effective medium ( f )</td>
<td>-</td>
<td>0.66</td>
</tr>
<tr>
<td>Tarnish shell thickness ( d_{sh} (\text{nm}) )</td>
<td>-</td>
<td>0.3</td>
</tr>
</tbody>
</table>

4.2 LPRs of Ag islands grown on faceted α-Al₂O₃

These experimental results have been reported previously, where a simpler version of the analytic model was used [63]. The arbitrary scaling factor that was applied to the dipolar interaction is eliminated in the approach presented here. Figure 2(a) shows the real RAS response and figure 2(b) the real part of the pseudo-dielectric function in the \( xz \)- and \( yz \)-optical planes determined by SE, all spectra being measured in the ambient. The dielectric function of Ag₂S tarnish films was used for the dielectric shell in equation (9a) [64]. The tarnish grows slowly and a shell thickness of 0.3 nm was chosen, consistent with previous work [55], which produced a small red shift of <0.1 eV in the spectra. The proportions of the effective medium used were one-third substrate and two-thirds ambient. The RAS and SE data were modeled using the same parameters.

The experimental data are compared with the model parameters in table 3. The average values of the Ag NP size, shape and distribution, with error estimates, for the arrays were obtained from the SEM images. The much smaller, isotropic NPs on the terraces are omitted from the analysis, as discussed in previous work [18, 63]. The average NP layer thickness in the model is thus smaller than the experimentally estimated thickness of the deposited layer. There is good agreement with the RAS line shape in figure 2(a), with the positions and relative intensities of the LPRs being well reproduced. The experimental peak widths are broader than the model, however, due to the dispersion in NP size. The peak width is dominated by the NP geometry for this system, because the Ag bulk plasmon inelastic scattering length of ~25 nm is larger than the island dimensions. No significant quadrupolar structure is observed, in agreement with previous work, which showed that tarnishing of Ag NPs suppressed quadrupolar effects [55]. The model SE response in figure 2(b) shows the same general characteristics as the RAS for the \( x \)- and \( y \)-LPRs, but the model predicts a smaller \( z \)-LPR intensity than is observed. This probably reflects the limitation of the simple approach used to account for the overestimate of the dipolar interaction normal to the surface, as discussed in section 3.2. In contrast to the RAS measurements, the smaller isotropic NPs on the terraces should contribute to the overall SE response, but no additional features are observed, probably due to the smearing out of the resonances due to NP size dispersion.
4.3 LPRs of Ag islands grown on native-oxide-covered rippled Si(0 0 1)

The inset in figure 3(a) shows that the NPs are less well ordered than the previous examples, with the NPs assembling in wavy lines on the surface. Figure 3(a) shows the real RAS response and figure 3(b) the real part of the pseudo-dielectric function determined from SE measurements in the $xz$-plane (red) and the $yz$-plane (black), with model spectra (solid lines); the inset uses a mixed $a$-Si/SiO$_2$ substrate dielectric function.

Figure 3(b) shows the effect of using an average of $a$-Si and SiO$_2$ for the substrate response, which produces better agreement but is unphysical, merely being used to illustrate the substrate problem. Figure 4 shows a typical TEM cross-section of such samples, where the separation of the NPs from the rippled substrate by the SiO$_2$ native layer is clearly seen [65]. A more complete model would need to include the effect of the native oxide, but this is not straightforward for rippled substrates.

The experimental data are compared with the model parameters in table 4. The average values of the Ag NP size, shape and distribution, with error estimates, for the arrays were obtained from the SEM images. As with the previous system, there is good agreement with the RAS line shape in figure 3(a), with the positions and relative intensities of the LPRs being well reproduced, and the experimental peak widths being broader than the model due to the dispersion in NP size. No significant quadrupolar structure is observed.

For RAS, the simple approach of neglecting the native oxide contribution works sufficiently well, probably because RAS suppresses the isotropic substrate contribution, and the ambient and native oxide dielectric functions are similar. For SE, it is clear from figure 3(b) that the substrate needs to be better modeled to allow useful LPR parameters to be extracted. The advantage of using RAS for more complex substrates is clear, although this sacrifices information about the $z$-LPR.

5. Discussion

The analytic model produces very good agreement with experiment for $x$- and $y$-LPRs from a range of NP materials, shapes and distributions, from different substrates, and for samples with and without capping layers. The NP dimensions range over an order of magnitude, while the NP density ranges over two orders of magnitude. The modeled RAS response, which is only sensitive to the $x$- and $y$-LPRs and which also suppresses the substrate response, agrees very well with all the
Table 4. Parameters for Ag NPs grown on native-oxide-covered rippled Si(0 0 1). Estimated errors are given in parentheses.

<table>
<thead>
<tr>
<th>Experiment</th>
<th>Model</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_x$ (nm)</td>
<td>8.5(2.5)</td>
</tr>
<tr>
<td>$R_y$ (nm)</td>
<td>6.5(1.5)</td>
</tr>
<tr>
<td>$R_z$ (nm)</td>
<td>-</td>
</tr>
<tr>
<td>$l_x$ (nm)</td>
<td>25(5)</td>
</tr>
<tr>
<td>$l_y$ (nm)</td>
<td>28(6)</td>
</tr>
<tr>
<td>Island density $\rho = 1/l_x l_y \text{ (nm}^2$)</td>
<td>1400(400)</td>
</tr>
<tr>
<td>Average NP layer thickness (nm)</td>
<td>-</td>
</tr>
<tr>
<td>RAS scaling factor</td>
<td>-</td>
</tr>
<tr>
<td>Effective medium $f$</td>
<td>-</td>
</tr>
<tr>
<td>Tarnish shell thickness $d_{th}$ (nm)</td>
<td>-</td>
</tr>
</tbody>
</table>

Acknowledgments

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Appendix. $\Delta$, $L_a$ and $L_f$ matrices

For the systems investigated, the principle axes of the layers are aligned with the laboratory axes, the incident beam is in the ambient or vacuum, and the angle of incidence is $\theta$. The capping layer and NP layer $\Delta$ matrix becomes

$$
\Delta = \begin{bmatrix}
0 & 0 & 0 & 1 - (\sin^2 \theta/\varepsilon_z)
\end{bmatrix}
$$

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$$
\Delta = \begin{bmatrix}
0 & 0 & 0 & 1 - (\sin^2 \theta/\varepsilon_z)
\end{bmatrix}
$$

The capping layer was isotropic in the systems studied: $\varepsilon_s = \varepsilon_x = \varepsilon_y = \varepsilon_{ap}$. The NP layer is anisotropic: $\varepsilon_s = \varepsilon_x^1; \varepsilon_y = \varepsilon_y^1; \varepsilon_z = \varepsilon_z^1$; with $\varepsilon^l$ given by equations (10a) and (10b). The inverse of the incident matrix, and the matrix describing exit into the substrate, are [59]

$$
L_a^{-1} = \begin{bmatrix}
0 & \frac{1}{2} & -\frac{1}{2} \sec \theta & 0 \\
0 & \frac{1}{2} & \frac{1}{2} \sec \theta & 0 \\
\frac{1}{2} \sec \theta & 0 & 0 & \frac{1}{2} \\
-\frac{1}{2} \sec \theta & 0 & 0 & \frac{1}{2}
\end{bmatrix}
$$

$$
L_f = \begin{bmatrix}
0 & 0 & \sqrt{1 - (\sin^2 \theta/\varepsilon_b)} & 0 \\
1 & 0 & 0 & 0 \\
-\sqrt{\varepsilon_b - \sin^2 \theta} & 0 & 0 & 0 \\
0 & 0 & \sqrt{\varepsilon_b} & 0
\end{bmatrix}
$$

References
